INSTITUTE OF AERONAUTICAL ENGINEERING
(Autonomous)
Dundigal, Hyderabad - 500043
COMPUTER SCIENCE AND ENGINEERING
TUTORIAL QUESTION BANK

| Course Title | ANALOG AND DIGITAL ELECTRONICS |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Course Code | AECB05 |  |  |  |  |
| Programme | B.Tech |  |  |  |  |
| Semester | THREE |  |  |  |  |
| Course Type | Core |  |  |  |  |
| Regulation | IARE - R18 |  |  |  |  |
| Course Structure | Theory |  |  | Practical |  |
|  | Lectures | Tutorials | Credits | Laboratory | Credits |
|  | 3 | 1 | 4 | - | - |
| Chief Coordinator | Ms. M Lavanya, Assistant Professor |  |  |  |  |

## COURSE OBJECTIVES:

Students will try to learn:

| I | The Fundamental knowledge of the operational principles and characteristics of semiconductor <br> devices and their applications. |
| :---: | :--- |
| II | The basic concept of number systems, boolean algebra and optimized implementation of <br> combinational and sequential circuits. |
| III | The perceive subsequent studies in the area of microprocessors, microcontrollers, VLSI design <br> and embedded systems effectively use of fundamentals of digital electronics. |

COURSE OUTCOMES:
At the end of the course students should be able to:

| Course Outcomes |  | Knowledge <br> Level <br> (Bloom's <br> Taxonomy) |
| :---: | :--- | :--- |
| CO1 | Recall the properties of semiconductor materials which form the basis for the <br> formation of PN junction diode. | Remember |


| CO2 | Illustrate the volt-ampere characteristics of semiconductor devices for finding <br> cut-in voltage, static, resistance and capacitance. | Understand |
| :--- | :--- | :---: |
| CO3 | Apply the PN junction characteristics for the diode <br> applications such as switch and rectifiers. | Apply |
| CO4 | Explain half wave and full wave rectifier circuits with filter and without <br> filters for conversion of alternating current in to direct current. | Understand |
| CO5 | Interpret DC and AC load line analysis of different amplifiers <br> for optimal operating level regardless of input, load placed on the device. | Understand |
| CO6 | Analyze the input and output characteristics of transistor configurations and <br> small signal h-parameter model for determining the input - output resistances, <br> current gain and voltage gain | Analyze |
| CO7 | Compare the binary decimal, octal and hexadecimal number systems in <br> terms of basic arithmetic operations. | Analyze |
| CO8 | Identify the functionality of logic gates, parity code and hamming code <br> techniques for error detection and correction of single bit in digital systems. | Apply |
| CO9 | Apply Boolean postulates and theorems, k-map and tabular methods for <br> obtaining minimized Boolean expressions. | Apply |
| CO10 | Develop the gate level combinational circuits to build adders, subtractors, <br> multiplexers, demultiplexers, encoders and decoders. | Apply |
| CO11 | Describe the operation of Flip-Flops and latches for constructing sequential <br> circuits. | Understand |
| CO12 | Implement the synchronous\& asynchronous counters for memory storing <br> applications. | Apply |

## MAPPING OF EACH CO WITH PO(s), PSO(s):

| Course | Program Outcomes |  |  |  |  |  |  |  |  |  |  |  | Program Specific Outcomes |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 1 | 2 | 3 |
| CO 1 | 1 | - | - | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 2 | 3 | 2 | - | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 3 | - | 2 | - | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 4 | 3 | - | - | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 5 | 3 | - | 2 | - | - | - | - | - | - | - | - | - | 3 | - | - |
| CO 6 | 3 | - | 1 | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 7 | 1 | - | - | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 8 | 3 | 1 | - | - | - | - | - | - | - | - | - | - | - | - | - |
| CO 9 | 3 | 2 | - | - | - | - | - | - | - | - | - | - | 3 | - | - |
| CO 10 | 3 | 1 | - | - | - | - | - | - | - | - | - | - | - | - | - |


| CO 11 | 3 | - | 2 | - | - | - | - | - | - | - | - | - | - | - | - |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| CO 12 | - | 2 | 2 | - | - | - | - | - | - | - | - | - | 3 | - | - |
| TOTAL | $\mathbf{2 6}$ | $\mathbf{1 0}$ | $\mathbf{7}$ | - | - | - | - | - | - | - | - | - | 9 | - | - |
| AVERAGE | $\mathbf{2 . 6}$ | $\mathbf{1 . 6}$ | $\mathbf{1 . 7}$ | - | - | - | - | - | - | - | - | - | $\mathbf{3}$ | - | - |

TUTORIAL QUESTION BANK

| MODULE-I |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| DIODE AND APPLICATIONS |  |  |  |  |
| PART-A(Short Answer Questions) |  |  |  |  |
| S.NO | QUESTION | $\begin{gathered} \text { Blooms } \\ \text { Taxonomy } \end{gathered}$ level | How does this subsume the level | Course outcomes |
| 1 | Find the static resistance of PN diode from V-I characteristics. | Remember | -- | CO 1 |
| 2 | Define Fermi level. | Remember | -- | CO 1 |
| 3 | Define depletion region? | Remember | -- | CO 2 |
| 4 | List the Applications of diode. | Remember | -- | CO 3 |
| 5 | Outline the V-I characteristics of PN junction diode. | Understand | This would require the learner to recall the behavior of PN junction with applied bias. Then outline V-I characteristics of diode | CO 2 |
| 6 | List the differences between ideal diode and practical diode. | Remember | -- | CO 1 |
| 7 | How diffusion capacitance is occurred in PN junction diode. | Remember | -- | CO 1 |
| 8 | Show the transition capacitance in PN junction diode. | Remember | -- | CO 1 |
| 9 | Explain drift current in PN diode. | Understand | This would require the learner to recall the conduction of diode in biasing. Then explain drift current component in PN diode | CO 1 |
| 10 | Define efficiency and mention the efficiency of HWR and FWR. | Remember | -- | CO 3 |
| 11 | Illustrate the load line analysis of diode. | Understand | This would require the learner to recall the diode characteristics. Then relate load line to V-I characteristics of diode | CO 2 |
| 12 | How diode acts as switch. | Understand | This would require the learner to recall the diode operation. Then explain how diode is used as switch | CO 3 |


| 13 | Show the expression of ripple factor of half wave rectifier. | Understand | This would require the learner to recall rectifier formula and relate it. | CO 3 |
| :---: | :---: | :---: | :---: | :---: |
| 14 | What is the dynamic resistance of PN junction diode. | Remember | -- | CO 2 |
| 15 | List the types of rectifiers. | Remember | -- | CO 3 |
| 16 | Classify the recovery times in PN diode. | Understand | This would require the learner to recall the switching times of diode. Then list the recovery times of PN diode | CO 1 |
| 17 | What is the forward recovery time of PN junction diode. | Understand | This would require the learner to recall the switching times of diode. Then write the expression for forward recovery time | CO 1 |
| 18 | Show the circuit for half wave rectifier using PN junction diode. | Remember | -- | CO 3 |
| 19 | What is the need for a filter in rectifier? | Remember | -- | CO 3 |
| 20 | Define cut-in voltage? | Remember | -- | CO 3 |
| PART-B(Long Answer Questions) |  |  |  |  |
| 1 | Outline the V-I characteristics of p-n junction diode for forward bias and reverse bias voltages and represent the static and dynamic resistance of the diode in the characteristic curve. | Understand | This would require the learner to recall the V-I characteristics based on applied bias. Then illustrate the ideal and practical resistances. | CO 2 |
| 2 | Summarize the static and dynamic resistances of a PN diode. | Understand | This would require the learner to recall the resistances of diode. Then contrast static and dynamic resistances | CO 2 |
| 3 | Explain the following terms for a PN diode 1. Load line 2. Diode switching times. 3. Reverse saturation current. | Understand | This would require the learner to recall the diode operation. Then explain the terms due to the effect of load and temperature applied on diode | CO 2 |
| 4 | Demonstrate the working of half-wave rectifier with circuit diagram and waveforms. | Understand | This would require the learner to recall the rectifier operation. Then demonstrate the half wave rectifier. | CO 3 |
| 5 | Illustrate transition capacitance and Diffusion capacitance With suitable expression. | Understand | This would require the learner to recall the biasing of diode then illustrate the effect of capacitances. | CO 1 |
| 6 | Illustrate the working of bridge full wave rectifier with circuit diagram and waveforms. | Understand | This would require the learner to recall the rectifier function then explain the bridge rectifier function using diodes. | CO 3 |
| 7 | Explain the operation of PN - junction diode under forward bias and reverse bias condition and Sketch the V-I characteristics of $\mathrm{p}-\mathrm{n}$ junction diode | Understand | This would require the learner to recall the V-I characteristics based on applied bias. | CO 3 |


| 8 | Explain the differences between Static and dynamic resistances of a $\mathrm{p}-\mathrm{n}$ diode. | Understand | This would require the learner to recall the rectifier operation. Then explain how bridge rectifier will work using diodes. | CO 3 |
| :---: | :---: | :---: | :---: | :---: |
| 9 | Explain difference between intrinsic and extrinsic semiconductor. | Remember | -- | CO 1 |
| 10 | Discuss the following with respect to semiconductor: <br> i. doping ii dopant iii donor iv acceptor.. | Remember | -- | CO 1 |
| 11 | What is Rectification efficiency? Derive expression for the following Half wave rectifier Full wave rectifier | Understand | This would require the learner to recall rectifier formula. Then relate the factors related to half wave and full wave rectifiers. | CO 3 |
| 12 | Explain the temperature dependence of VI characteristics of PN diode? | Understand | This would require the learner to recall its formula. Then relate the factors to full wave rectifier. | CO 3 |
| 13 | Find the terms as referred to the half wave rectifier: <br> Efficiency <br> Average or D.C voltage <br> Ripple factor. | Remember | -- | CO 3 |
| 14 | Explain what is hole is. How do they move in intrinsic semiconductor? | Remember | -- | CO 1 |
| 15 | Find the terms as referred to the full wave rectifier: <br> PIV <br> TUF <br> Ripple factor. | Remember | -- | CO 3 |
| 16 | Find the ripple factor for the half wave rectifier with a shunt capacitor filter. | Remember | -- | CO 3 |
| 17 | List the merits and Demerits of half wave, full wave and bridge rectifier. | Remember | -- | CO 3 |
| 18 | Explain the formation of depletion region in an open circuited p-n junction with neat sketches. | Understand | This would require the learner to recall the construction of PN junction diode. Then explain how the depletion region is formed for unbiased | CO 1 |
| 19 | What is d.c load line and explain the d.c load line analysis of p -n junction diode with relevant expressions. | Understand | This would require the learner to recall the load line analysis for diode. Then explain the DC load line | CO 2 |
| 20 | Write the applications of p-n junction diode and explain how the p-n diode acts as a switch. | Understand | This would require the learner to recall the applications of diode understand the operation of diode and how it acts as a switch. | CO 3 |
| PART-C(Analytical Questions) |  |  |  |  |
| 1 | Find the value of D.C. resistance and A.C resistance of a Germanium junction diode at $25^{\circ} \mathrm{C}$ with reverse saturation current, | Remember | -- | CO 2 |


|  | $\mathrm{I}_{0}=25 \mu \mathrm{~A}$ and at an applied voltage of 0.2 V across the diode. |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| 2 | Find the value of D.C. resistance and A.C resistance of a Germanium junction diode at $250^{\circ} \mathrm{C}$ with reverse saturation current, Io $=5 \mu \mathrm{~A}$ and at an applied voltage of 0.2 V across the diode? | Remember | -- | CO 2 |
| 3 | The reverse saturation current of a silicon $\mathrm{p}-\mathrm{n}$ junction diode is 10 uA . Calculate the diode current for the forward-bias voltage of 0.6 v at $25^{\circ} \mathrm{C}$. | Understand | This would require the learner to recall, the formula of diode and then assign values for parameters and solve the given parameters | CO 2 |
| 4 | Determine the values of forward current in the case of P-N junction diode, with $\mathrm{I}_{0}=10$ $\mu \mathrm{AVf}=0.8 \mathrm{~V}$ at $\mathrm{T}=300^{\circ} \mathrm{K}$. Assume silicon diode? | Remember | -- | CO 3 |
| 5 | The voltage across a silicon diode at room temperature of 300 K is 0.7 V when 2 ma current flows through it. If the voltage increases to 0.75 v , Evaluate the diode current assuming VT=26mv. | Remember | -- | CO 3 |
| 6 | In a full wave rectifier ,the transformer rms secondary voltage from center tap to each end of the secondary is 50 V . The lad resistance is 900 ohms. If the diode resistance and transformer secondary winding resistance together has a resistance of 100 ohms , determine the average load current and RMS value of load current. | Remember | -- | CO 3 |
| 7 | A half wave rectifier is used to supply 24 V dc to a resistance load of 500 ohms and the diode has a forward resistance of 50 ohms. Calculate the maximum value of the ac voltage required at the input. | Remember | -- | CO 3 |
| 8 | A full wave rectifier delivers 50 W to a load of 200 ohms. If the ripple factor is $1 \%$, calculate the AC ripple voltage across the load. | Understand | This would require the learner to recall, the formula of full wave rectifier and then assign values for parameters and solve the given parameters | CO 3 |
| 9 | Determine the dynamic forward and reverse resistance of p-n <br> Junction silicon diode when the applied voltage is 0.25 V at $\mathrm{T}=300 \mathrm{~K}$ with give $\mathrm{I}_{0}=2$ $\mu \mathrm{A}$ ? | Remember | -- | CO 1 |
| 10 | A $230 \mathrm{~V}, 50 \mathrm{~Hz}$ voltage is applied to the primary of a $4: 1$ step down transformer used in a bridge rectifier having a load resistance of 600 ohms .Assuming the diodes to be ideal ,determine (a) dc output voltage,(b) dc powered delivered to the load ,(c) PIV, and(d) output frequency | Remember | -- | CO 3 |


| BIPOLAR JUNCTION TRANSISTOR (BJT) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PART-A(Short Answer Questions) |  |  |  |  |
| 1 | Show the Bipolar Junction Transistor and label the terminals of transistor. | Understand | This would require the learner to recall the construction of transistor. Then outline the terminals of transistor | CO 5 |
| 2 | Show the Q point in transistor characteristics. | Understand | This would require the learner to recall the operating point. Then outline the transistor operation | CO 5 |
| 3 | Outline the symbols of NPN and PNP transistor. | Understand | This would require the learner to identify the symbolic representation of transistors then show the symbols of NPN and PNP transistors | CO 5 |
| 4 | Show AC load line of transistor. | Understand | This would require the learner to recall the load line analysis then find AC load line from characteristics of transistor. | CO 5 |
| 5 | Relate $\alpha, \beta$ and $\gamma$ in bipolar transistor. | Understand | This would require the learner to recall the amplification factors in transistor. then relate the $\alpha, \beta$ and $\gamma$. | CO 5 |
| 6 | List out h parameters in CE configuration. | Remember | -- | CO 6 |
| 7 | List the h parameters in CB configuration. | Remember | -- | CO 6 |
| 8 | Recall base width modulation in bipolar junction transistor. | Remember | -- | CO 6 |
| 9 | Show h parameters in CC configuration. | Understand | This would require the learner to recall the hybrid model of transistor. Then outline the parameters from h model | CO 6 |
| 10 | Show current amplification factor for CE configuration. | Understand | This would require the learner to recall the transistor operation. Then show amplification factor for CE based Transistor. | CO 6 |
| 11 | When the transistor is said to be in cut-off region. | Remember | -- | CO 6 |
| 12 | List the various regions in a transistor and compare them with respect to doping and width. | Remember | -- | CO 6 |
| 13 | Outline the output characteristics of NPN transistor in Common Emitter configuration. | Understand | This would require the learner to recall the transistor operation. Then show the output characteristics in CE configuration | CO 6 |
| 14 | Show the circuit of a Common Base configuration using PNP transistor. | Understand | This would require the learner to recall the transistor configuration then construct the configuration using Common base | CO 6 |


| 15 | Show the relation between $\mathrm{I}_{\mathrm{C}}, \beta, \mathrm{I}_{\mathrm{B}}$ and $\mathrm{I}_{\text {CBO }}$ in Bipolar Junction transistor. | Understand | This would require the learner to recall the transistor operation. Then relate the parameters. | CO 5 |
| :---: | :---: | :---: | :---: | :---: |
| 16 | What is the significance of the arrow-head in the transistor symbol? | Remember | -- | CO 5 |
| 17 | Relate the active region for NPN transistor using Common Emitter configuration. | Understand | This would require the learner to recall the transistor operation. Then relate the active region for NPN transistor | CO 5 |
| 18 | Label the various current components in a BJT. | Remember | -- | CO 5 |
| 19 | Name the current controlling devices. | Remember | -- | CO 5 |
| 20 | Relate de and ac load lines of transistor. | Remember | -- | CO 5 |
| PART-B(Long Answer Questions) |  |  |  |  |
| 1 | Explain the various current components in an NPN bipolar junction transistor With a neat diagram. | Understand | This would require the learner to recall the transistor operation. Then relate the current components in BJT. | CO 5 |
| 2 | What factors are to be considered for selecting the operating point Q for an amplifier | Apply | This would require learner to recall the load line analysis, understand what factors are considered and apply those formulate to find operating point Q for an amplifier. | CO 2 |
| 3 | Demonstrate the working of transistor in common emitter configurations and draw its input and output characteristics. | Understand | This would require the learner to recall the transistor construction. Then demonstrate the CE configuration | CO 6 |
| 4 | Explain working of transistor in common base configurations and draw its input and output characteristics. | Understand | This would require the learner to recall the transistor construction. Then demonstrate the CB configuration | CO 6 |
| 5 | Explain working of transistor in common collector configurations and draw its input and output characteristics. | Understand | This would require the learner to recall the transistor construction. Then demonstrate the CC configuration | CO 6 |
| 6 | Show the h-parameters of a bipolar junction transistor in a small signal model. | Understand | This would require the learner to recall the hybrid model of transistor. Then show the parameters of BJT from h-model | CO 6 |
| 7 | The common-base dc current gain of a transistor is 0.967 . If the emitter current is 10 mA , Solve the value of base current. | Understand | This would require the learner to recall its formula for assigning the values to solve the base current | CO 6 |
| 8 | The transistor has $\mathrm{IE}=20 \mathrm{~mA}$ and $\alpha=0.18$. Find the values of $\mathrm{I}_{\mathrm{C}}$ and $\mathrm{I}_{\mathrm{B}}$. | Remember | -- | CO 6 |
| 9 | Determine the h-parameters for the common base configuration using NPN transistor. | Understand | This would require the learner to recall the hybrid model of common base configuration. Then show the parameters of BJT from h-model | CO 6 |


| 10 | Explain the CE configuration using h parameter model. | Understand | This would require the learner to recall the hybrid model of common Emitter configuration. Then show the parameters of CE amplifier | CO 6 |
| :---: | :---: | :---: | :---: | :---: |
| 11 | Illustrate the common collector configuration of BJT with relevant figures and explain its input and output characteristics. | Understand | This would require the learner to recall the transistor construction. Then demonstrate the CC configuration | CO 6 |
| 12 | Explain the DC and AC load line analysis of a BJT. | Understand | This would require the learner to recall the load line analysis then illustrate Dc and AC load line for transistor. | CO 5 |
| 13 | Draw the small-signal model of common base BJT amplifier. Derive expressions for voltage gain, input resistance current gain and output resistance? | Remember | This would require to recall the physical scenario to find theh-model to the CE configuration of transistor | CO 6 |
| 14 | Draw the small-signal model of common collector BJT amplifier. Derive expressions for voltage gain, input resistance, current gain and output resistance? | Remember | -- | CO 6 |
| 15 | Draw the small-signal model of common emitter BJT amplifier. Derive expressions for voltage gain, input resistance current gain and output resistance? | Remember | -- | CO 6 |
| 16 | For a transistor circuit having $\alpha=0.98, \mathrm{I}_{\text {СВ }}$ $=I_{C O}=5 \mu \mathrm{~A}$, and $\mathrm{I}_{\mathrm{B}}=100 \mu \mathrm{~A}$, find $\mathrm{I}_{\mathrm{C}}$ and $\mathrm{I}_{\mathrm{E}}$. | Remember | -- | CO 6 |
| 17 | Define following  <br> i) Active Region <br> ii) Cut off region <br> iii) Saturation region | Understand | This would require the learner to recall the amplification of the transistor and understand how transistor operates in three regions. | CO 6 |
| 18 | The dc current gain of a transistor in CE mode is 100 . Find its dc current gain in CB mode. | Remember | -- | CO 6 |
| 19 | List the formulae used to convert CE hparameters to CB and CC | Remember | -- | CO 6 |
| 20 | Explain the small signal model of BJT CE Amplifier and derive expressions for voltage gain, input resistance current gain and output resistance of CE amplifier? | Understand | This would require the learner to recall the formulas for amplification factors in transistor. Then solve the parameters. | CO 6 |
| PART-C(Analytical Questions) |  |  |  |  |
| 1 | A CE Amplifier is drawn by a voltage source of internal resistance Rs=800 $\Omega$ and $R L=1000 \Omega$. The h-parameters are hie $=$ $1 \mathrm{k} \Omega$ hre $=2 \times 10-4, \mathrm{hfe}=50$ and hoe $=25 \mu \mathrm{~A} / \mathrm{V}$. Determine Ai, Ri, Av, Ro. Using exact analysis and approximate analysis. | Understand | This would require the learner to recall the formulas for amplification factors in transistor. Then solve the parameters. | CO 6 |


| 2 | Determine Ai, Ri, Av, Ro For a CE Amplifier using NPN transistor with hie= $1200 \Omega$ hre $=0$ hfe $=36$ and hoe $=2 \times 10-6$ Mhos. Rs $=500 \Omega$ and $R L=2.5 \mathrm{k} \Omega$ (neglect the effect of biasing circuit) | Apply | This would require recall the h parameters, understand relevant $h$ model parameters and apply the h model to the CE amplifier for measuring the gain parameters. | CO 6 |
| :---: | :---: | :---: | :---: | :---: |
| 3 | For a CE Amplifier , if $\mathrm{Rs}=\mathrm{RL}=1000 \Omega$, hie $=1100 \Omega$ hre $=2.5 \times 10-4 \mathrm{hfe}=50$ and hoe $=25 \mu \mathrm{~A} / \mathrm{V}$. Find Ai, Ri, Av Ais , and Avs | Apply | This would require recall expression for performance of a CE amplifier parameters (understand) in terms of h model and apply to measure the gain parameters. | CO 6 |
| 4 | A transistor operating in CB configuration has Ic $=2.98 \mathrm{~mA}, \mathrm{I}_{\mathrm{E}}=3 \mathrm{~mA}$ and $\mathrm{I}_{\mathrm{C} 0}=$ 0.01 mA . What current will flow in the collector circuit of this transistor when connected in CE configuration with base current of $30 \mu \mathrm{~A}$. | Understand | This would require the learner to recall the transistor operation under CE mode. Then solve the collector current. | CO 6 |
| 5 | The transistor has a $\mathrm{I}_{\mathrm{E}}=10 \mathrm{~mA}$ and $\alpha=0.98$. Determine the value of $\mathrm{I}_{\mathrm{C}}$ AND $\mathrm{I}_{\mathrm{B}}$ | Remember | ---- | CO 6 |
| 6 | The h-parameters of a transistor in the CE amplifier mode are hie $=1100 \Omega$ hre $=$ $2.5 \times 10-4 \mathrm{hfe}=50$ and $h o e=25 \mu \mathrm{~A} / \mathrm{V}$. determine the current gain and input resistance of the amplifier for a load resistance $\mathrm{RL}=1 \mathrm{~K} \Omega$ | Remember | ---- | CO 6 |
| 7 | For a CB Configuration Rs=1200 $\Omega, \mathrm{RL}=1000 \Omega$.The h-parameters are hib= $22 \Omega \mathrm{hrb}=3 \times 10-4 \mathrm{hfb}=-0.98$ and hob $=0.5 \mu \mathrm{~A} / \mathrm{V}$ Find Ai, Ri, Av Ais, Ro and Avs using exact analysis. | Remember | ---- | CO 6 |
| 8 | A transistor connected in CC configuration and its h-parameters are hie $=1100 \Omega$ hre $=$ $2.5 \times 10-4 \mathrm{hfe}=-50$ and hoe $=24 \mu \mathrm{~A} / \mathrm{V}$ Find $\mathrm{Ai}, \mathrm{Ri}$, and Av | Understand | This would require the learner to recall the transistor operation in CE mode. Then solve the Ai, Ri, and Av of the CE Amplifier. | CO 6 |
| 9 | For a transistor circuit having $\alpha=0.97$ find the value of $\beta$. If $\beta=200$, find the value of $\alpha$. | Remember | -- | CO 6 |
| 10 | The h -parameters of a transistor used as an amplifier in the CE configuration are are hie $=800 \Omega$ hre $=5.4 \times 10-4$ hfe $=-50$ and hoe $=80 \times 10^{-6}$. If the load resistance is 5 k $\Omega$ Find Ai, Ri ,Ro and Av | Understand | This would require the learner to recall the transistor operation in CB mode. Then solve the Ai, Ri, and Av of the CB Amplifier. | CO 6 |
| MODULE - III |  |  |  |  |
| NUMBER SYSTEMS |  |  |  |  |
| PART - A (Short Answer Questions) |  |  |  |  |
| 1 | Write short notes on binary number systems. | Remember | --- | CO 7 |
| 2 | Explain 1's and 2's complement. | Understand | Learner to recall binary numbers and find the 1's and 2's complement. | CO 7 |
| 3 | Discuss octal number system. | Understand | --- | CO 7 |


| 4 | Convert the octal numbers into binary, decimal and Hexadecimal numbers (45.5)8, (32.2)8. | Understand | --- | CO 7 |
| :---: | :---: | :---: | :---: | :---: |
| 5 | Show an example to convert gray code to binary code. | Remember | --- | CO 7 |
| 6 | Describe a short note on four bit BCD codes | Remember | --- | CO 7 |
| 7 | Illustrate about unit -distance code? State where they are used. | Understand | Learner to recall the operation of gray code and find the unit distance code. | CO 7 |
| 8 | List the applications of error correcting codes. | Remember | --- | CO 8 |
| 9 | Convert 10101101.0111 to octal equivalent and hexadecimal equivalent. | Remember | --- | CO 7 |
| 10 | Give the examples of unit distance codes | Remember | --- | CO 7 |
| CIE-II |  |  |  |  |
| 1 | Which gates are called as universal gate justify. | Understand | Learner to recall the operation of logic gates and find universal gates. | CO 8 |
| 2 | State DeMorgan's theorem | Remember | --- | CO 9 |
| 3 | State Duality theorem. | Remember | --- | CO 9 |
| 4 | Draw the symbols and truth tables of XOR and XNOR gates | Remember | --- | CO 9 |
| 5 | Define sum of products and product of sum | Remember | --- | CO 9 |
| 6 | State and prove the distributive property of Boolean algebra. | Remember | --- | CO 9 |
| 7 | Simplify $\mathrm{ABC}+\mathrm{AB}^{\prime} \mathrm{C}+\mathrm{ABC}^{\prime}$ | Understand | Learner to recall the operation of Boolean postulates and theorems and Solve the expression. | CO 9 |
| 8 | Convert the given expression in standard SOP form $\mathrm{Y}=\mathrm{AC}+\mathrm{AB}+\mathrm{BC}$ | Understand | Learner to recall the operation of conversions and understand the standard form and expand the expression. | CO 9 |
| 9 | Convert the given expression in standard POS form $\mathrm{Y}=(\mathrm{A}+\mathrm{B})(\mathrm{B}+\mathrm{C})(\mathrm{A}+\mathrm{C}) .$ | Understand | Learner to recall the operation of conversions and understand the standard form and expand the expression. | CO 9 |
| 10 | List out the basic logic gates with truth tables | Remember | --- | CO 9 |
| PART-B (Long Answer Questions) |  |  |  |  |
| 1 | Explain error occurred in data transmission can be detected using parity bit? | Understand | Learner to recall the operation of parity generation and understand the error detecting code. | CO 8 |
| 2 | Define weighted codes and non weighted codes with examples? | Remember | --- | CO 8 |
| 3 | Explain what do you mean by error detection and correcting code with examples. | Understand | Learner to recall the operation of parity generation and understand the error detecting code. | CO 8 |


| 4 | Explain the gray to binary and binary- togray conversion with examples | Understand | Learner to recall binary and gray code and understand the conversion using Ex-or gate logic. | CO 7 |
| :---: | :---: | :---: | :---: | :---: |
| 5 | Explain the conversion of AND/OR/NOT logic to NAND/ NOR logic with example. | Understand | This would require the learner to recall the operation of logic gate and understand the conversion to universal gates. | CO 8 |
| 6 | Explain Self complemented codes. | Remember | --- | CO 7 |
| 7 | Differentiate between BCD code and 2421 code and XS-3. | Understand | Learner to recall the concept of BCD code, 2421 code and XS-3 code and list the differences. | CO 7 |
| 8 | Solve the given 8bit data word 01011011, generate the 12 bit composite word for the hamming code that corrects and detects single errors. | Apply | Learner to recall the Binary information and understand concept of hamming code and apply in solving the given data. | CO 8 |
| 9 | Write the first 10 decimal digits in base 3 and base 16 . | Remember | --- | CO 7 |
| 10 | A device transmits the binary data using even parity, the message is 1011001 . Identify the receiver receives the correct data or not. | Remember | --- | CO 8 |
| CIE-II |  |  |  |  |
| 1 | Convert the given expression in standard POS form $\mathrm{Y}=(\mathrm{A}+\mathrm{B})(\mathrm{B}+\mathrm{C})(\mathrm{A}+\mathrm{C}) .$ | Understand | This would require the learner to recall the operation of conversion to standard form and expand the expression. | CO 9 |
| 2 | Give the Boolean expressions, symbols and truth tables for following gates, <br> i) AND ii) NOR iii) EX-OR iv) OR v) EXNOR. | Remember | --- | C08 |
| 3 | Implement all the logic gates using NAND gate. | Apply | This would require the learner to recall the operation of logic gate and understand the conversion to NAND gate process and apply it for all logic gates. | C08 |
| 4 | Construct all the logic gates using NOR gate. | Apply | This would require the learner to recall the operation of logic gate and understand the conversion to NOR gate process and apply it for all logic gates | C08 |
| 5 | Solve the canonical SOP form of the following functions. <br> i) $\mathrm{Y}(\mathrm{A}, \mathrm{B})=\mathrm{A}+\mathrm{B}$. ii) $\mathrm{Y}(\mathrm{A}, \mathrm{B}, \mathrm{C}, \mathrm{D})=$ $A B+A C D$ | Remember | ----. | CO 9 |
| 6 | Simplify the expression $\mathrm{Z}=\mathrm{AB}+\mathrm{AB}$ '. ( $\left.\mathrm{A}^{\prime} \mathrm{C}^{\prime}\right)^{\prime}$ | Understand | This would require the learner to recall the operation of conversion to standard form and simplify the expression. | CO 9 |
| 7 | Simplify the following 3 variable expression using Boolean algebra $\mathrm{Y}=$ | Understand | This would require the learner to recall the operation of conversion to | CO 9 |


|  | $\Pi \mathrm{M}(3,5,7)$. |  | standard form and simplify the expression. |  |
| :---: | :---: | :---: | :---: | :---: |
| 8 | Simplify the following 3 variable expression using Boolean algebra $\mathrm{Y}=$ $\sum \mathrm{m}(1,3,5,7)$. | Understand | This would require the learner to recall the operation of conversion to standard form and simplify the expression. | CO 9 |
| 9 | Explain standard SOP and POS forms with examples | Remember | --- | CO 9 |
| 10 | State and prove Boolean theorems and properties. | Remember | --- | CO 9 |
| PART-C (Problem Solving and Critical Thinking Questions) |  |  |  |  |
| 1 | Convert the following Hexadecimal number to their Decimal equivalent (EAF1)16. | Understand | This would require the learner to recall the concept of binary and decimal number system and find the conversion. | CO 7 |
| 2 | What is the gray code equivalent of the Hex Number 3A7. Find 9's complement of (25.639) 10. | Remember | --- | CO 7 |
| 3 | Implement 7 bit hamming code for given message 1010 by using odd parity. | Apply | This would require the learner to recall the concept of odd parity and understand the using of parity bits in hamming code and to implement hamming code for given data | CO 8 |
| 4 | Perform the subtraction using 1's complement and 2's Complement <br> i) $(11010)_{2}-(10000)_{2}$ <br> ii) $(1000100)_{2}-(1010100)_{2}$ | Remember | --- | CO 7 |
| 5 | Convert following hexadecimal number to decimal, <br> i) F2816 ii) BC216 | Remember | --- | CO 9 |
| CIE-II |  |  |  |  |
| 1 | Implement $\mathrm{Y}=\mathrm{AB}^{\prime}+\mathrm{A}^{\prime} \mathrm{B}$ using 2 input NAND gates | Apply | This would require the learner to recall the concept of logic gates and understand the logic of NAND gate to implement the expression. | CO 8 |
| 2 | Simplify using postulates and theorems of Boolean algebra <br> i) $\quad\left(X+Y^{\prime}+X Y\right)\left(X+Y^{\prime}\right) X^{\prime} Y$ <br> ii) $\quad(\mathrm{AB}+\mathrm{C}+\mathrm{D})\left(\mathrm{C}^{\prime}+\mathrm{D}\right)\left(\mathrm{C}^{\prime}+\mathrm{D}+\mathrm{E}\right)$ | Understand | This would require the learner to recall the concept of postulates and theorems of Boolean algebra to simplify the given expression. | CO 9 |
| 3 | For each of the following expressions, construct the corresponding logic circuit using AND/OR/INVERT logic. <br> i) $\mathrm{Y}=\mathrm{A} \overline{\mathrm{B}(\mathrm{C}+\mathrm{D})}$ <br> ii) $\mathrm{Z}=(\mathrm{W}+\mathrm{PQ})^{\prime}$ | Remember | --- | CO 9 |
| 4 | Implement $\mathrm{Y}=\mathrm{AB}{ }^{\prime}+\mathrm{A}^{\prime} \mathrm{B}$ using 2 input NOR gates | Apply | This would require the learner to recall the concept of logic gates and understand the logic of NOR gate to implement the expression. | CO 8 |
| 5 | Realize X-OR operation a)NAND gate b)NOR gate | Apply | This would require the learner to recall the concept of X-OR gate and | CO 8 |


|  |  |  | understand the logic of NAND and NOR gates to implement the X-OR operation. |  |
| :---: | :---: | :---: | :---: | :---: |
| MODULE - IV |  |  |  |  |
| MINIMIZATION OF BOOLEAN FUNCTIONS |  |  |  |  |
| PART - A (Short Answer Questions) |  |  |  |  |
| 1 | What is K-Map and State the limitations of karnaugh map. | Remember | ----- | CO 9 |
| 2 | Construct a $16 \times 1$ Mux using only $2 \times 1$ Mux | Understand | This would require the learner to recall concept of multiplexer and understand the design procedure of Boolean functions using multiplexer and this procedure can implement 16x1 Mux using 2 x1 Mux with proper selection lines. | CO 10 |
| 3 | Define even and odd parity. | Remember | ---- | CO 10 |
| 4 | What is decoder? How do you convert a decoder in to a De- Multiplexer | Remember | ---- | CO 10 |
| 5 | What is multiplexer? Give the size of a multiplexer. | Remember | ---- | CO 10 |
| 6 | Define Implicant, Prime Implicant and Essential Prime Implicant. | Remember | ---- | CO 9 |
| 7 | Sketch the Full adder using Logic Gates. | Understand | This would require the learner to recall the operation of full adder its truth table and draw the Full Adder circuit using logic gates. | CO 10 |
| 8 | Draw the Half subtractor using NAND Gates. | Understand | This would require the learner to recall the operation of half subtractor its truth table and draw the half subtractor circuit using NAND gates. | CO 10 |
| 9 | What is Demultiplexer? Give the size of a Demultiplexer. | Remember | --- | CO 10 |
| 10 | List some of the applications of multiplexer and de multiplexer | Remember | ---- | CO 10 |
| 11 | Draw a Full adder using NOR Gates. | Understand | This would require the learner to recall the operation of full adder its truth table and understand the Full Adder using NOR gates. | CO 10 |
| 12 | Draw Half subtractor using NOR Gates | Understand | This would require the learner to recall the operation of Half Subtractor its truth table and understand the Half Subtractor using NOR gates. | CO 10 |
| 13 | Draw a Full subtractor using NAND Gates. | Understand | This would require the learner to recall the operation of full subtractor its truth table and | CO 10 |


|  |  |  | understand the Full Subtractor using NAND gates. |  |
| :---: | :---: | :---: | :---: | :---: |
| 14 | Draw a Full subtractor using NOR Gates. | Understand | This would require the learner to recall the operation of full Subtractor its truth table and understand the Full Adder using NOR gates. | CO 10 |
| 15 | State the truth table for full adder. | Remember | ---- | CO 10 |
| 16 | Draw a Full adder using NAND Gates. | Understand | This would require the learner to recall the operation of full adder its truth table and understand. The Full Adder using NAND gates. | CO 10 |
| 17 | Explain the differences between multiplexer and de multiplexer | Understand | This would require the learner to recall the operation of MUX and De-MUX, truth table and logic circuit. and distinguish between them in terms of number of inputs, outputs and their applications. | CO 10 |
| 18 | Explain about J-K (NOR gates) Latch? | Understand | This would require the learner to recall the logic circuit and truth table of JKlatch using NOR gates and explain the operation JK-latch for various combinations of J and k inputs. | CO 11 |
| 19 | Write the characteristic equations of SR, JK, D and T flip-flops. | Remember | ----- | CO 11 |
| 20 | Explain the differences between synchronous and asynchronous latch? | Understand | This would require the learner to recall the concept of synchronous and asynchronous latch and find the differences between them. | CO 11 |
| PART-B (Long Answer Questions) |  |  |  |  |
| 1 | Explain the design procedure of Synchronous Sequential circuit with an example? | Understand | This would require the learner to recall the concept of synchronous conversion and the design procedure of combinational logic circuits. And explain the design of code converters by taking an example. | CO 12 |
| 2 | Write short notes on shift register? <br> Mention its application along with the Serial Transfer in 4-bit shift Registers? | Understand | This would require the learner to recall the basic structure and operation of shift register. And explain the operation in serial transfer mode also its applications. | CO 12 |
| 3 | Explain about Binary Ripple Counter? What is MOD counter? | Understand | This would require the learner to recall the concept of asynchronous counter and mod counter. Then explain the operation of binary ripple counter. | CO 12 |
| 4 | How do you convert Jk- Flip Flop to SRFlip Flop | Understand | This would require the learner to recall operation of JK and SR flip-flops and their truth tables. Then convert the JK flip-flop into SR flip-flop using | CO 11 |


|  |  |  | excitation tables and characteristic tables. |  |
| :---: | :---: | :---: | :---: | :---: |
| 5 | How do you convert T- Flip Flop to SR- Flip Flop | Understand | This would require the learner to recall the operation of T and SR flip-flops and their truth tables. Then convert the T flip-flop into SR flip-flop using excitation tables and characteristic tables. | CO 11 |
| 6 | How do you convert D- Flip Flop to JK- Flip Flop | Understand | This would require the learner to recall operation of D and JK flipflops and their truth tables. Then convert the D flip-flop into JK flipflop using excitation tables and characteristic tables. | CO 11 |
| 7 | Explain the JK and Master slave Flip-flop? Give its timing waveform? | Understand | This would require the learner to recall the operation of JK flip-flop and race around condition. Then explain how the race around condition is eliminated in Master slave flip-flop with the help of timing waveforms. | CO 11 |
| 8 | Explain the Ripple counter design procedure. Also design a decade counters. | Understand | This would require the learner to recall the design procedure of ripple counter. And understand the decade counter which can count 10 pulses. | CO 12 |
| 9 | Construct a 3 bit ring counter? Discuss how ring counters differ from twisted ring counter? | Apply | This would require the learner to recall the operation of Counters and understand the design procedure of synchronous counter to construct a Ring counter and discuss the differences between Ring and Twisted Ring counter. | CO 12 |
| 10 | Explain the JK - Flip-flop with the help of a logic diagram and characteristic table? | Understand | This would require the learner to recall the logic diagram and understand the characteristic table of JK flip-flop. | CO 11 |
| 11 | Construct a logic circuit to convert gray code to binary code. | Apply | This would require the learner to recall the concept of gray code, binary code and understand the design procedure of combinational logic circuits to implement a logic circuit to convert gray code to its equivalent binary code using logic gates. | CO 10 |
| 12 | Construct a logic circuit to convert binary code to gray code. | Apply | This would require the learner to recall the concept of gray code, binary code and understand the design procedure of combinational logic circuits to implement a logic circuit to convert binary code to its equivalent gray code using logic gates. | CO 10 |


| 13 | Realize the Boolean expression for full <br> subtractor and draw the logic circuit. | Understand | This would require the learner to <br> recall the concept of full subtractor. <br> Then derive the output equations of <br> full subtractor and draw the circuit <br> using logic gates. | CO 10 |
| :--- | :--- | :--- | :--- | :---: |
| 14 | Implement the circuit to produce the octal <br> number for given 4 bit binary number. | Apply | This would require the learner to recall <br> the concept of octal number system <br> understand the design procedure of <br> combinational logic circuits. Then can <br> implement a logic circuit to produce <br> the octal number or the given 4 bit <br> binary number. | CO 10 |
| 15 | Explain 4-bit carry look-ahead adder with <br> necessary diagram and relevant <br> expressions. | Understand | This would require the learner to recall <br> the concept of 4- bit carry look-ahead <br> adder. Then explain the operation of 4- <br> bit carry look-ahead adder and how it <br> reduces the propagation delay <br> compared to 4-bit parallel binary adder. | CO 10 |
| 16 | Simplify the following Boolean expressions <br> using K- map and implement them using <br> logic gates. <br> F (A, B, C, D)= AB'C'+ AC + A'CD', <br> F (W, X, Y, Z) = W'X'Y'Z' + WXY'Z' <br> + W'X'YZ + WXYZ | Understand | This would require the learner to recall <br> the concept of simplifying a Boolean <br> function using Karnaugh map. <br> Understand the simplified function <br> using logic gates. | CO 9 |
| 17 | Implement a 64:1 MUX using 8:1 MUXs. | Apply <br> Explain the working of 3-bit <br> asynchronous up-down counter with <br> necessary waveform and truth table. | This would require the learner to recall <br> the Boolean functions using <br> multiplexer and understand the design <br> procedure of boolen function using <br> multiplexer to implement 64:1 Mux <br> using 8:1 Mux with proper selection <br> lines. | CO 10 |


|  |  |  | a 3-bit asynchronous up-down counter. |  |
| :---: | :---: | :---: | :---: | :---: |
| 2 | How do you convert Jk- Flip Flop to SRFlip Flop | Understand | This would require the learner to recall operation of SR and JK flipflops and their truth tables. Then convert the SR flip-flop into JK flipflop using excitation tables and characteristic tables. | CO 12 |
| 3 | Construct a 4-bit binary counter (using D flip flops) which counts all possible odd numbers only? | Apply | This would require the learner to recall the operation of D flip-flop understand the design procedure of counter and to construct a counter which can count all possible odd numbers only using D flip-flops. | CO 12 |
| 4 | Develop a Modulo-12 Synchronous up counters using T-Flip Flops and draw the Circuit diagram. | Apply | This would require the learner to recall the operation of T flip-flop and understand the design procedure of synchronous counter to design a Modulo-12 counter using T flip-flops. | CO 12 |
| 5 | How do you convert Jk- Flip Flop to DFlip Flop | Understand | This would require the learner to recall operation of D and JK flip-flops and their truth tables. Then convert the D flip-flop into JK flip-flop using excitation tables and characteristic tables. | CO 11 |
| 6 | Construct a MOD-5 synchronous counter using flip flops and Implement it? Also draw the timing diagram? | Apply | This would require the learner to recall the operation of flip-flops to understand the design procedure of synchronous counter and to construct a Mod-5 counter which can count the given sequence using JK flip-flops. | CO 12 |
| 7 | How do you convert SR- Flip Flop to JKFlip Flop | Understand | This would require the learner to recall operation of JK and SR flipflops and their truth tables. Then convert the SR flip-flop into JK flipflop using excitation tables and characteristic tables. | CO 12 |
| 8 | Build a 4- bit Twisted Ring counter using JK flip-flop? | Apply | This would require the learner to recall the concept of synchronous counter. Understand the design procedure to build a 4-bit twisted ring counter using JK flip-flops. | CO 12 |
| 9 | Implement MOD5 up and Down counter? | Apply | This would require the learner to recall the concept of synchronous counter. Understand the design procedure to implement a Mod-5 Up and Down counter | CO 12 |
| 10 | How do you convert Jk- Flip Flop to TFlip Flop | Understand | This would require the learner to recall operation of T and JK flipflops and their truth tables. Then convert the D flip-flop into JK flip- | CO 11 |


|  |  |  | flop using excitation tables and characteristic tables. |  |
| :---: | :---: | :---: | :---: | :---: |
| MODULE - V |  |  |  |  |
| Sequential Circuits Fundamentals |  |  |  |  |
| PART - A (Short Answer Questions) |  |  |  |  |
| 1 | Write the Differences combinational and sequential logic circuits? | Understand | This would require the learner to recall the block diagram of combinational and sequential circuits. Then find the differences between them. | CO 11 |
| 2 | Explain basic difference between a shift register and counter? | Understand | This would require the learner to recall the basic structure and operation of shift register and counter. Then explain the differences between them. | CO12 |
| 3 | Illustrate applications of shift registers? | Understand | This would require the learner to recall the basic structure and operation of shift register. Then can find its applications. | CO 12 |
| 4 | Define bidirectional shift register? | Remember | ---- | CO 12 |
| 5 | Write the Differences Flip-flop and latch? | Understand | This would require the learner to recall the concept of latch and flipflop. Then find the differences between them. | CO 11 |
| 6 | Define Counter? | Remember | ---- | CO 12 |
| 7 | Classify the basic types of counters? | Understand | This would require the learner to recall the definition of counter. Then find the various types of counters. | CO 12 |
| 8 | Write the Differences the advantages and disadvantages of ripple counters? | Understand | This would require the learner to recall the operation of ripple counter, and write the advantages and disadvantages of ripple counter over synchronous counter. | CO 12 |
| 9 | Describe the applications of counters? | Understand | This would require the learner to recall the basic structure and operation of counters. Then can find its real time applications. | CO 12 |
| 10 | Draw D-latch using NAND? | Remember | --- | CO 11 |
| 11 | Explain the operation of gated SR latch. | Understand | This would require the learner to recall the logic circuit and truth table of SR-latch. Then can explain the operation of SR-latch for various combinations of $S$ and $R$ inputs | CO 11 |
| 12 | Define race around condition? How it can be avoided? | Understand | This would require the learner to recall the operation of JK flip-flop. Then can find the occurrence of race | CO 11 |


|  |  |  | around condition in JK flip-flop and also can discuss the remedy for it. |  |
| :---: | :---: | :---: | :---: | :---: |
| 13 | Explain about S-R (NOR gates) Latch? | Understand | This would require the learner to recall the logic circuit and truth table of SR-latch using NOR gates. Then explain the operation SR-latch for various combinations of $S$ and $R$ inputs. | CO 11 |
| 14 | Explain about S-R (NAND gates) Latch? | Understand | This would require the learner to recall the logic circuit and truth table of SR-latch using NAND gates. Then explain the operation SR-latch for various combinations of $S$ and $R$ inputs. | CO 11 |
| 15 | Draw The truth table of gated D-Latch? | Understand | This would require the learner to recall the logic circuit and operation of D-latch and understand the truth table of D-latch based on the operation. | CO 11 |
| 16 | List the advantages and disadvantages of Johnson counter. | Remember | ---- | CO 12 |
| 17 | Draw The truth table of gated SR-Latch? | Understand | This would require the learner to recall the logic circuit and operation of SR-latch and understand the truth table of SR-latch based on the operation. | CO 11 |
| 18 | Explain about J-K (NOR gates) Latch? | Understand | This would require the learner to recall the logic circuit and truth table of JK-latch using NOR gates. Then explain the operation JK-latch for various combinations of J and k inputs. | CO 11 |
| 19 | Write the characteristic equations of SR, JK, D and T flip-flops. | Understand | This would require the learner to recall the truth tables of $\mathrm{SR}, \mathrm{JK}, \mathrm{D}$ and T flip-flops. Understand the characteristic equations using K-map | CO 11 |
| 20 | Distinguish between synchronous and asynchronous latch? | Understand | This would require the learner to recall the concept of synchronous and asynchronous latch. Then explain the differences between them. | CO 11 |
| PART-B (Long Answer Questions) |  |  |  |  |
| 1 | Explain the design procedure of Synchronous Sequential circuit with an example? | Understand | This would require the learner to recall the concept of synchronous conversion and the design procedure of combinational logic circuits. Then can explain the design of code converters by taking an example. | CO 12 |
| 2 | Write short notes on shift register? Mention its application along with the Serial Transfer in 4-bit shift Registers? | Understand | This would require the learner to recall the basic structure and operation of shift register. Then can | CO 12 |


|  |  |  | explain the operation in serial transfer mode also its applications. |  |
| :---: | :---: | :---: | :---: | :---: |
| 3 | Explain about Binary Ripple Counter? What is MOD counter? | Understand | This would require the learner to recall the concept of asynchronous counter and mod counter. Then explain the operation of binary ripple counter. | CO 12 |
| 4 | How do you convert Jk- Flip Flop to SRFlip Flop | Remember | ---- | CO 11 |
| 5 | How do you convert T- Flip Flop to SR- Flip Flop | Remember | ---- | CO 11 |
| 6 | How do you convert D- Flip Flop to JK- Flip Flop | Remember | ---- | CO 11 |
| 7 | Explain the JK and Master slave Flip-flop? Give its timing waveform? | Understand | This would require the learner to recall the operation of JK flip-flop and race around condition. Then explain how the race around condition is eliminated in Master slave flip-flop with the help of timing waveforms. | CO 11 |
| 8 | Explain the Ripple counter design procedure. Also design a decade counters. | Understand | This would require the learner to recall the design procedure of ripple counter. Then with the help of design procedure and understand the decade counter which can count 10 pulses. | CO 12 |
| 9 | Construct a 3 bit ring counter? Discuss how ring counters differ from twisted ring counter? | Understand | This would require the learner to recall the operation of Ring and Twisted Ring counter also the design procedure of synchronous counter. Then with the help of design procedure and understand the Ring counter and discuss the differences between Ring and Twisted Ring counter. | CO 12 |
| 10 | Define JK - Flip-flop with the help of a logic diagram and characteristic table? | Understand | This would require the learner to recall the logic diagram and understand characteristic table of JK flip-flop. | CO 11 |
| 11 | Explain the operation of RS and JK flipflops with functional diagram and Truth tables. Also derive the characteristic equations. | Understand | This would require the learner to recall the logic diagram and characteristic table of RS and JK flipflop. Then with the help of truth table and explain the characteristic equation of RS and JK flip-flop using K-map | CO 11 |
| 12 | With the help of neat circuit diagram explain the working of Master Slave JK flip flop and also explain how race around condition is eliminated in it. | Understand | This would require the learner to recall the logic circuit and operation of Master slave JK flip-flop. Then explain how the race around condition is eliminated in Master slave flip-flop. | CO 11 |


| 13 | Explain the operation of D and T flip-flops with functional diagram and Truth tables. Also derive the characteristic equations | Understand | This would require the learner to recall the logic diagram and characteristic table of D and T flipflop. and understand the characteristic equation of D and T flip-flop. | CO 11 |
| :---: | :---: | :---: | :---: | :---: |
| 14 | Develop a cyclic BCD up synchronous counter using T flip-flops | Apply | This would require the learner to recall the operation of T flip-flop understand the design procedure of synchronous counter ,to construct a BCD up synchronous counter using T flip-flops. | CO 12 |
| 15 | Construct the transition table for the following flip-flops SR-F/F, D-F/F | Apply | This would require the learner to recall the logic diagram and understand characteristic table of $D$ and SR flip-flop to develop the transition tables which can be used in conversion of flip-flops. | CO 11 |
| 16 | Explain with a suitable logic and timing diagram: <br> i) Serial-in-serial out shift register <br> ii) Parallel-in-parallel-out unidirectional shift register. | Understand | This would require the learner to recall the concept of shift register. Then explain the operation of 4-bit shift register in SISO and PIPO modes with the help of logic and timing diagram. | CO 12 |
| 17 | Construct a mod-11 up ripple counter using T flip-flops. | Apply | This would require the learner to recall the operation of T flip-flop and understand the design procedure of asynchronous counter to construct a Modulo-11ripple up counter using T flip-flops. | CO 12 |
| 18 | Explain with a neat diagram and truth table, 4- bit SIPO shift register to store binary number 1011. | Understand | This would require the learner to recall the concept of shift register. Then explain the operation of 4-bit shift register in SIPO mode with the help of truth table and logic circuit. | CO 12 |
| 19 | With neat logic diagram, explain the different modes of operation of universal shift register. | Understand | This would require the learner to recall the concept of universal shift register. Then explain its operation in different modes with the help of truth table and logic circuit. | CO 12 |
| 20 | With the help of a schematic diagram, explain how a serial shift register can be transformed into a (i) ring counter (ii) Johnson counter. | Understand | This would require the learner to recall the concept of serial shift register. Then explain how it can be converted into a ring counter and Johnson counter. | CO 12 |
| PART-C (Analytical Questions) |  |  |  |  |
| 1 | Explain the working of 3-bit asynchronous up-down counter with necessary waveform and truth table. | Understand | This would require the learner to recall the concept of asynchronous counter. Then explain the operation of a 3-bit asynchronous up-down counter. | CO 12 |


| 2 | Design a synchronous counter using JKFF to count the following sequence $0,2,5,6,0 \ldots$ undesired states $1,3,4,7$ must go to 0 on the next clock pulse. | Apply | This would require the learner to recall the operation of JK flip-flop understand the design procedure of synchronous counter to construct a counter which can count the given sequence using JK flip-flops. | CO 12 |
| :---: | :---: | :---: | :---: | :---: |
| 3 | Construct a 4-bit binary counter (using D flip flops) which counts all possible odd numbers only? | Apply | This would require the learner to recall the operation of D flip-flop and understand the design procedure of counter to construct a counter which can count all possible odd numbers only using D flip-flops. | CO 12 |
| 4 | Develop a Modulo-12 Synchronous up counters using T-Flip Flops and draw the Circuit diagram. | Apply | This would require the learner to recall the operation of T flip-flop and understand the design procedure of synchronous counter. to construct a Modulo-12 counter using T flipflops. | CO 12 |
| 5 | How do you convert Jk- Flip Flop to DFlip Flop | Remember | ----- | CO 11 |
| 6 | Construct a MOD-5 synchronous counter using flip flops and Implement it? Also draw the timing diagram? | Apply | This would require the learner to recall the concept of synchronous counter. understand the design procedure to construct a Mod-5 counter which can count the given sequence using JK flip-flops. | CO 12 |
| 7 | Design a counter with the sequence 0, , , 3, 7, 6, 4, 0 using JK FF | Apply | This would require the learner to recall the design procedure of synchronous counter understand the operation of JK-flip-flop. To construct a counter which can generate the given sequence using JK flip-flops? | CO 12 |
| 8 | Build a 4- bit Twisted Ring counter using JK flip-flop? | Apply | This would require the learner to recall the design procedure of synchronous counter and understand the design procedure to construct a 4bit twisted ring counter using JK flipflops. | CO 12 |
| 9 | Implement MOD5 up and Down counter? | Apply | This would require the learner to recall the design procedure of synchronous counter and understand of design procedure to construct a Mod-5 Up and Down counter | CO 12 |
| 10 | How do you convert Jk- Flip Flop to T- Flip Flop | Remember | --- | CO 11 |

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